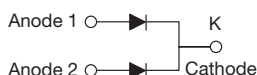
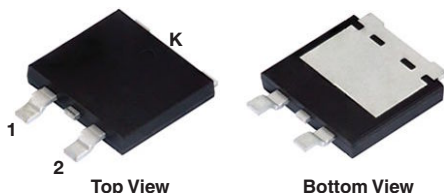


# Ultrafast Rectifier, 2 x 8 A FRED Pt®

## eSMP® Series SMPD (TO-263AC)



## FEATURES

- Ultrafast recovery time, reduced  $Q_{rr}$ , and soft recovery
- 175 °C maximum operating junction temperature
- For PFC CRM, snubber operation
- Low forward voltage drop
- Low leakage current
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified, meets JESD 201 class 2 whisker test
- Material categorization: for definitions of compliance please see [www.vishay.com/doc?99912](http://www.vishay.com/doc?99912)



**RoHS**  
COMPLIANT  
HALOGEN  
**FREE**

## DESIGN SUPPORT TOOLS AVAILABLE



3D Models

## PRIMARY CHARACTERISTICS

$I_{F(AV)}$	2 x 8 A
$V_R$	600 V
$V_F$ at $I_F$	0.94 V
$t_{rr}$	45 ns
$T_J$ max.	175 °C
Package	SMPD (TO-263AC)
Circuit configuration	Common cathode

## DESCRIPTION / APPLICATIONS

State of the art ultrafast recovery rectifiers specifically designed with optimized performance of forward voltage drop, ultrafast recovery time, and soft recovery.

The planar structure and the platinum doped life time control guarantee the best overall performance, ruggedness, and reliability characteristics.

These devices are intended for use in PFC, boost, in the AC/DC section of SMPS, freewheeling and clamp diodes.

Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce power dissipation in the switching element and snubbers.

## ABSOLUTE MAXIMUM RATINGS

PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Peak repetitive reverse voltage	$V_{RRM}$		600	V
Average rectified forward current	$I_{F(AV)}$	$T_{solder\ pad} = 149\text{ °C}$	16	A
			8	
Non-repetitive peak surge current	$I_{FSM}$	$T_J = 25\text{ °C}$ , 6 ms square pulse	200	
			105	

## ELECTRICAL SPECIFICATIONS ( $T_J = 25\text{ °C}$ unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Breakdown voltage, blocking voltage	$V_{BR}$ , $V_R$	$I_R = 100\text{ }\mu\text{A}$	600	-	-	V
Forward voltage, per diode	$V_F$	$I_F = 8\text{ A}$	-	1.1	1.4	
		$I_F = 8\text{ A}$ , $T_J = 150\text{ °C}$	-	0.94	1.15	
Reverse leakage current, per diode	$I_R$	$V_R = V_R$ rated	-	-	5	$\mu\text{A}$
		$T_J = 150\text{ °C}$ , $V_R = V_R$ rated	-	20	150	
Junction capacitance, per diode	$C_T$	$V_R = 600\text{ V}$	-	8	-	pF

<b>DYNAMIC RECOVERY CHARACTERISTICS</b> ( $T_J = 25\text{ }^{\circ}\text{C}$ unless otherwise specified)						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Reverse recovery time	$t_{rr}$	$I_F = 1\text{ A}$ , $dI_F/dt = 50\text{ A}/\mu\text{s}$ , $V_R = 30\text{ V}$	-	45	-	ns
		$I_F = 0.5\text{ A}$ , $I_R = 1\text{ A}$ , $I_{rr} = 0.25\text{ A}$	-	-	60	
		$T_J = 25\text{ }^{\circ}\text{C}$	-	70	-	
		$T_J = 125\text{ }^{\circ}\text{C}$	-	100	-	
Peak recovery current	$I_{RRM}$	$T_J = 25\text{ }^{\circ}\text{C}$	-	12	-	A
		$T_J = 125\text{ }^{\circ}\text{C}$	-	17	-	
Reverse recovery charge	$Q_{rr}$	$T_J = 25\text{ }^{\circ}\text{C}$	-	430	-	nC
		$T_J = 125\text{ }^{\circ}\text{C}$	-	850	-	

<b>THERMAL - MECHANICAL SPECIFICATIONS</b>						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Maximum junction and storage temperature range	$T_J, T_{Stg}$		-55	-	+175	$^{\circ}\text{C}$
Thermal resistance, per diode junction to solder pad	$R_{thJ-Sp}$		-	1.8	2.5	$^{\circ}\text{C}/\text{W}$
Approximate weight			0.55			g
			0.02			oz.
Marking device		Case style SMPD (TO-263AC)	16CDU06			

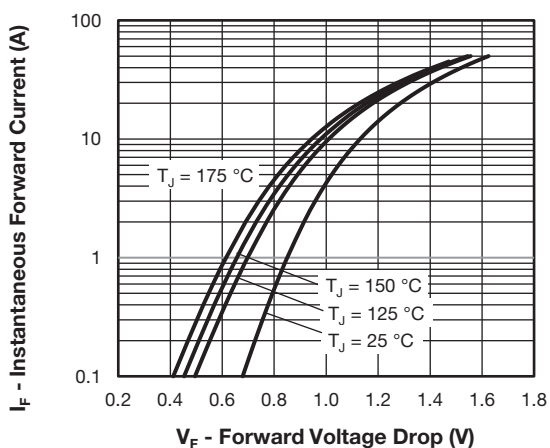


Fig. 1 - Typical Forward Voltage Drop Characteristics

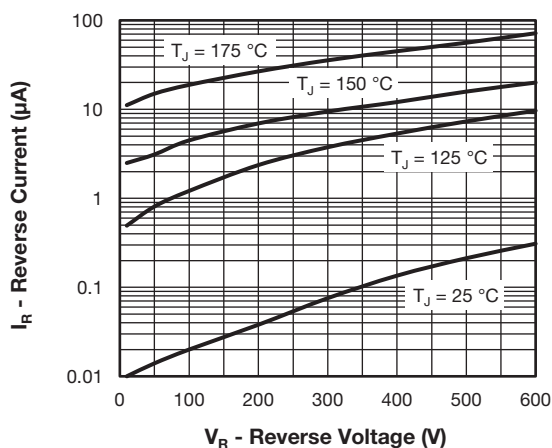


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

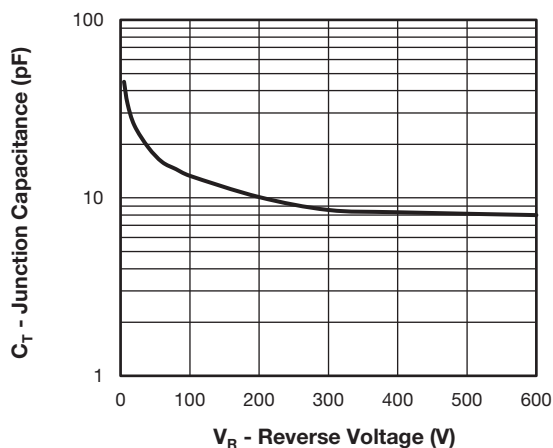


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

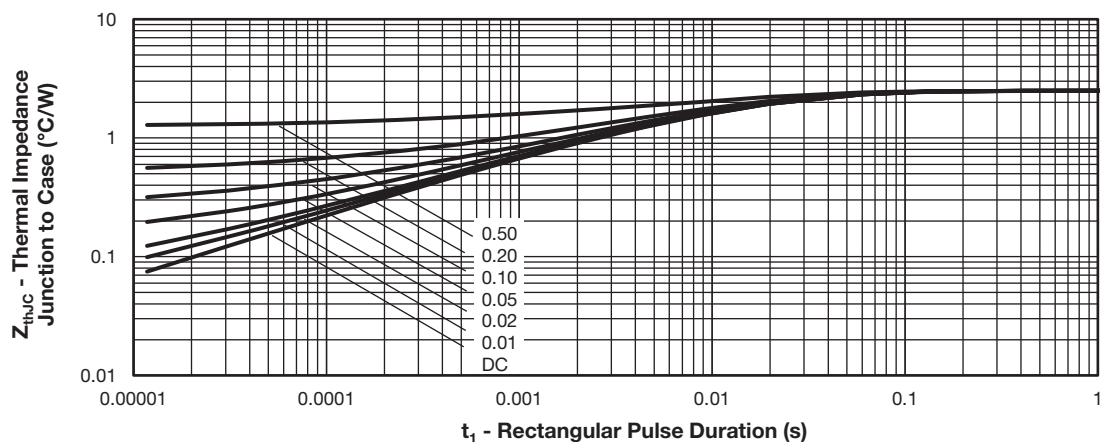
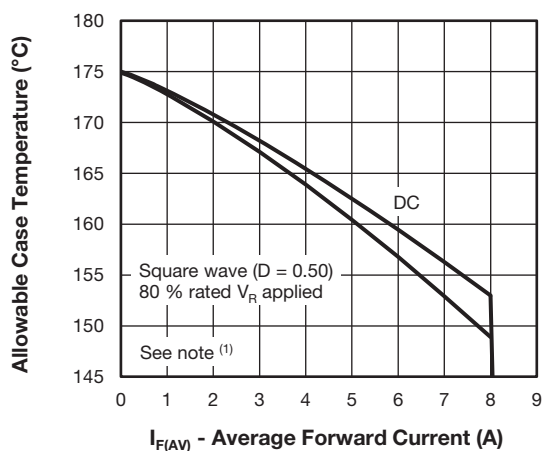

Fig. 4 - Maximum Thermal Impedance  $Z_{thJC}$  Characteristics


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

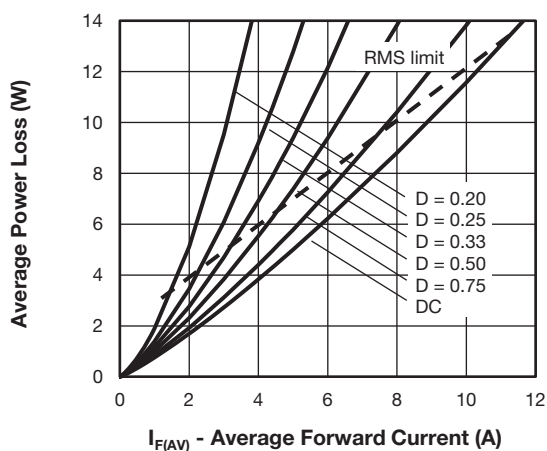


Fig. 6 - Forward Power Loss Characteristics

#### Note

- (1) Formula used:  $T_C = T_J - (P_d + P_{dREV}) \times R_{thJC}$ ;  
 $P_d$  = forward power loss =  $I_{F(AV)} \times V_{FM}$  at  $(I_{F(AV)}/D)$  (see fig. 5);  
 $P_{dREV}$  = inverse power loss =  $V_{R1} \times I_R (1 - D)$ ;  $I_R$  at  $V_{R1}$  = rated  $V_R$

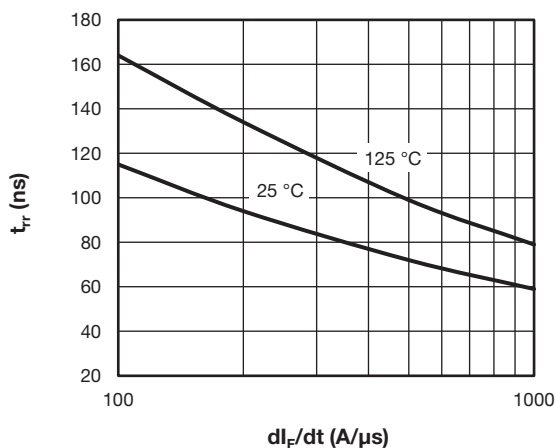
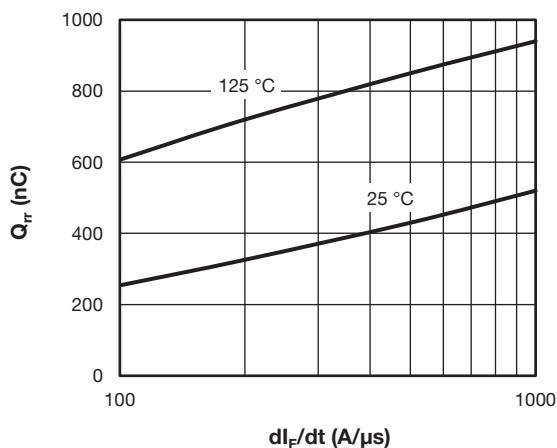
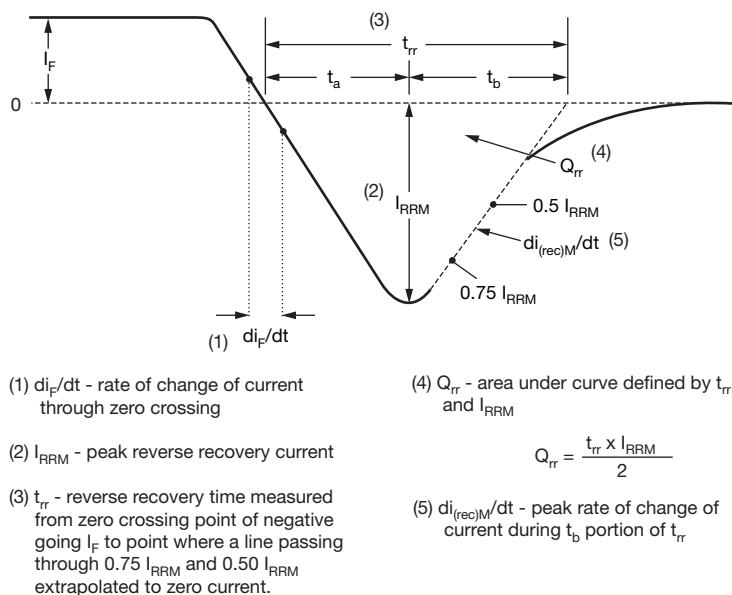

Fig. 7 - Typical Reverse Recovery Time vs.  $dI_F/dt$ 

Fig. 8 - Typical Stored Charge vs.  $dI_F/dt$ 


Fig. 9 - Reverse Recovery Waveform and Definitions

## ORDERING INFORMATION TABLE

Device code	VS-	16	C	D	U	06	H	M3
	1	2	3	4	5	6	7	8

- 1 - Vishay Semiconductors product
- 2 - Current rating (16 A)
- 3 - Circuit configuration:  
C = common cathode
- 4 - D = SMPD package
- 5 - Process type,  
U = ultrafast recovery
- 6 - Voltage code (06 = 600 V)
- 7 - H = AEC-Q101 qualified
- 8 - M3 = halogen-free, RoHS-compliant, and terminations lead (Pb)-free

### ORDERING INFORMATION (Example)

PREFERRED P/N	QUANTITY PER REEL	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION
VS-16CDU06HM3/I	2000	2000	13" diameter plastic tape and reel

## LINKS TO RELATED DOCUMENTS

Dimensions	<a href="http://www.vishay.com/doc?95604">www.vishay.com/doc?95604</a>
Part marking information	<a href="http://www.vishay.com/doc?95566">www.vishay.com/doc?95566</a>
Packaging information	<a href="http://www.vishay.com/doc?88869">www.vishay.com/doc?88869</a>
SPICE model	<a href="http://www.vishay.com/doc?96575">www.vishay.com/doc?96575</a>

## TO-263AC (SMPD)

**DIMENSIONS** in inches (millimeters)





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